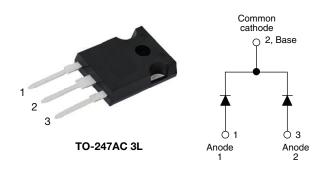
**Vishay Semiconductors** 

# Ultrafast Rectifier, 2 x 15 A FRED Pt<sup>®</sup>

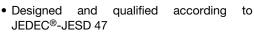


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PRIMARY CHARACTERISTICS									
I <sub>F(AV)</sub>	2 x 15 A								
V <sub>R</sub>	200 V								
V <sub>F</sub> at I <sub>F</sub>	0.85 V								
t <sub>rr</sub> typ.	See Recovery table								
T <sub>J</sub> max.	175 °C								
Package	TO-247AC 3L								
Circuit configuration	Common cathode								

### **FEATURES**

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current





RoHS COMPLIANT HALOGEN FREE

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

VS-MUR3020WT... is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage		V <sub>RRM</sub>		200	V				
Average rectified forward current	per leg	I		15					
Average rectified forward current total de		I <sub>F(AV)</sub>	Rated V <sub>R</sub> , T <sub>C</sub> = 150 °C	30	А				
Non-repetitive peak surge current per leg		I <sub>FSM</sub>	t <sub>p</sub> = 10 ms	200	A				
Peak repetitive forward current per leg		I <sub>FM</sub>	Rated $V_R$ , square wave, 20 kHz, $T_C = 150 \ ^\circ C$	30					
Operating junction and storage temperatures		T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	200	-	-					
Commend wellses	V	I <sub>F</sub> = 15 A	-	-	1.05	V				
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	-	0.85					
		$V_R = V_R$ rated	-	-	10					
Reverse leakage current	I <sub>R</sub>	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	- 500 μA						
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	55	-	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	12	-	nH				

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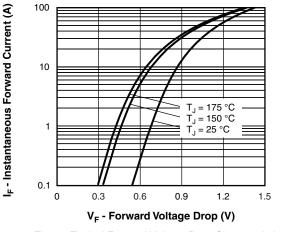
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ di}_F/\text{dt} =$	$I_F = 1.0 \text{ A}, \text{ di}_F/\text{dt} = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$			35				
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	22	-	ns			
		T <sub>J</sub> = 125 °C	]	-	39	-				
Pools receivers ourrent	1	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A di <sub>F</sub> /dt = 200 A/μs	-	1.6	-	А			
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$V_{\rm B} = 160 \text{ V}$	-	4.1	-	~			
Reverse recovery charge	0	T <sub>J</sub> = 25 °C	-n	-	19	-	-0			
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	90	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	-	1.5					
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-					
Woight			-	6.0	-	g				
Weight			-	0.21	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC 3L	MUR3020WT							



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Fig. 1 - Typical Forward Voltage Drop Characteristics

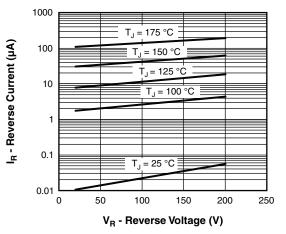


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

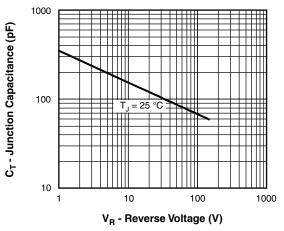


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

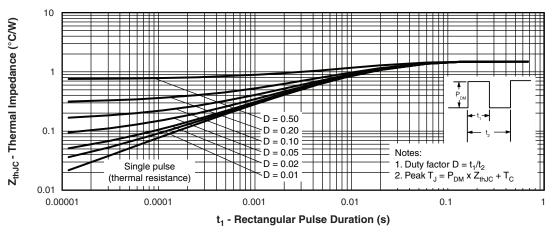
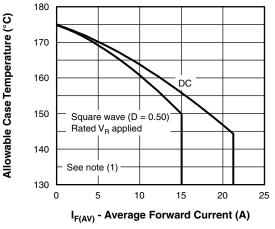
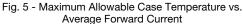


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics







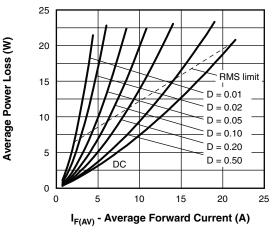
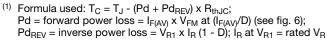


Fig. 6 - Forward Power Loss Characteristics

#### Note



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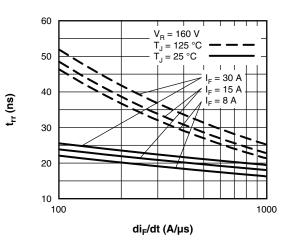


Fig. 7 - Typical Reverse Recovery Time vs. di<sub>F</sub>/dt

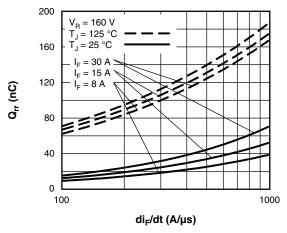


Fig. 8 - Typical Stored Charge vs. di<sub>F</sub>/dt

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# VS-MUR3020WT-N3

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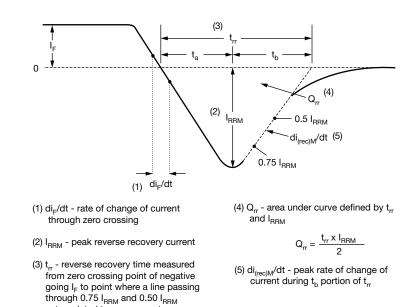


Fig. 9 - Reverse Recovery Waveform and Definitions

extrapolated to zero current.

#### **ORDERING INFORMATION TABLE**

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Device code	VS-	MUR	30	20	νт	-N3
		2	(3)	4	(5)	6
		$\bigcirc$	$\bigcirc$	niconduc	$\bigcirc$	$\bigcirc$
	2 -		,	JR serie		
	3 - 4 -			ng (30 = ng (20 =		
	5 -		•	r tap (dı		
	6 -	- Env	ironmer	ntal digit	:	
		-N3	= halog	en-free,	RoHS-	complia

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MUR3020WT-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS								
Dimensions www.vishay.com/doc?96138								
Part marking information	www.vishay.com/doc?95007							

State
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**Vishay Semiconductors** 

TO-247AC 3L

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51 BSC 0.217 BSC		' BSC		
D1	13.08	-	0.515	-	4							

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension Q

Revision: 20-Jun-17

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